

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (π -MOS V)

2SK4023

Switching Regulator, DC/DC Converter

- 4 V gate drive
- Low drain-source ON-resistance: $R_{DS(ON)} = 4.0 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 0.8 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 100 \mu\text{A}$ (max) ($V_{DS} = 450 \text{ V}$)
- Enhancement mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Characteristic | | Symbol | Rating | Unit |
|--|---------------------------------------|-----------|------------|------------------|
| Drain-source voltage | | V_{DSS} | 450 | V |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | V_{DGR} | 450 | V |
| Gate-source voltage | | V_{GSS} | ± 30 | V |
| Drain current | DC (Note 1) | I_D | 1 | A |
| | Pulse ($t = 1 \text{ ms}$) (Note 1) | I_{DP} | 2 | |
| Drain power dissipation ($T_c = 25^\circ\text{C}$) | | P_D | 20 | W |
| Single-pulse avalanche energy (Note 2) | | E_{AS} | 122 | mJ |
| Avalanche current | | I_{AR} | 1 | A |
| Repetitive avalanche energy (Note 3) | | E_{AR} | 2 | mJ |
| Channel temperature | | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage temperature range | | T_{stg} | -55 to 150 | $^\circ\text{C}$ |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

| Characteristic | Symbol | Max | Unit |
|--|----------------|------|--------------------|
| Thermal resistance, channel to case | $R_{th(ch-c)}$ | 6.25 | $^\circ\text{C/W}$ |
| Thermal resistance, channel to ambient | $R_{th(ch-a)}$ | 125 | $^\circ\text{C/W}$ |

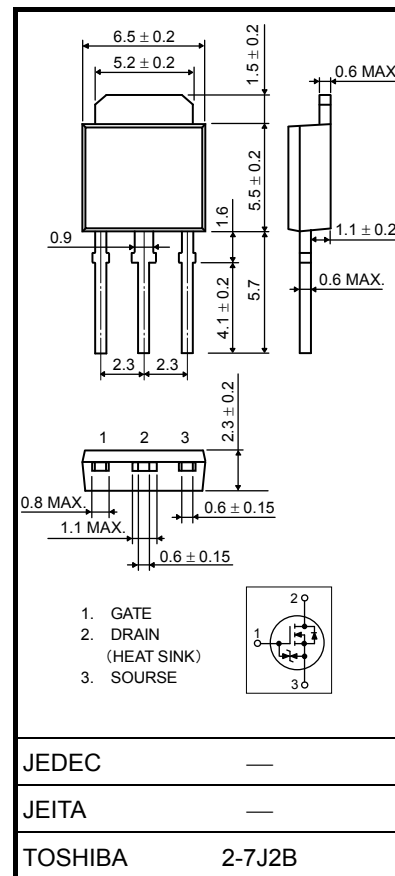
Note 1: Ensure that the channel temperature does not exceed 150°C .

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^\circ\text{C}$, $L = 203 \text{ mH}$, $I_{AR} = 1 \text{ A}$, $R_G = 25 \Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

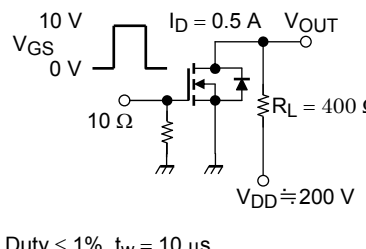
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.36 g (typ.)

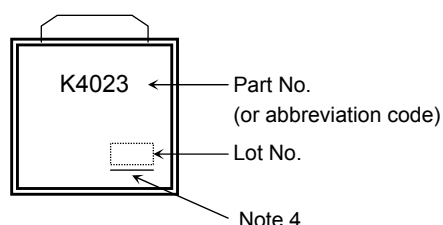
Electrical Characteristics (Ta = 25°C)

| Characteristic | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|---------------|---------------|--|----------|------|----------|---------------|
| Gate leakage current | | I_{GSS} | $V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$ | — | — | ± 10 | μA |
| Gate-source breakdown voltage | | $V_{(BR)GSS}$ | $I_G = \pm 10 \mu\text{A}, V_{DS} = 0 \text{ V}$ | ± 30 | — | — | V |
| Drain cutoff current | | I_{DSS} | $V_{DS} = 450 \text{ V}, V_{GS} = 0 \text{ V}$ | — | — | 100 | μA |
| Drain-source breakdown voltage | | $V_{(BR)DSS}$ | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$ | 450 | — | — | V |
| Gate threshold voltage | | V_{th} | $V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$ | 2.0 | — | 4.0 | V |
| Drain-source ON-resistance | | $R_{DS(ON)}$ | $V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$ | — | 4.0 | 4.6 | Ω |
| Forward transfer admittance | | $ Y_{fs} $ | $V_{DS} = 10 \text{ V}, I_D = 0.5 \text{ A}$ | 0.3 | 0.8 | — | S |
| Input capacitance | | C_{iss} | $V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | — | 180 | — | pF |
| Reverse transfer capacitance | | C_{rss} | | — | 2 | — | |
| Output capacitance | | C_{oss} | | — | 20 | — | |
| Switching time | Rise time | t_r |  | — | 7 | — | ns |
| | Turn-on time | t_{on} | | — | 15 | — | |
| | Fall time | t_f | | — | 30 | — | |
| | Turn-off time | t_{off} | | — | 70 | — | |
| Total gate charge | | Q_g | $V_{DD} \doteq 360 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$ | — | 5 | — | nC |
| Gate-source charge | | Q_{gs} | | — | 3 | — | |
| Gate-drain charge | | Q_{gd} | | — | 2 | — | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

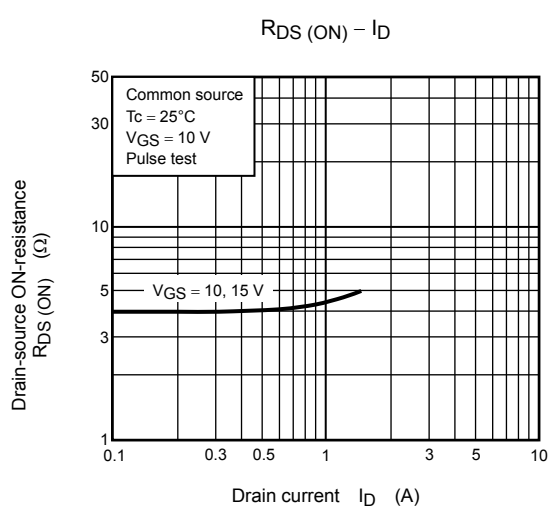
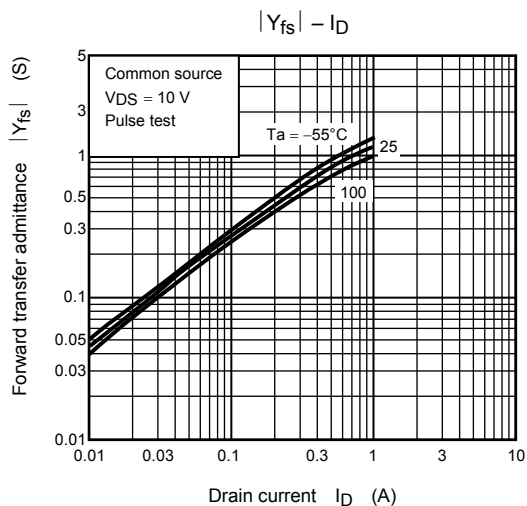
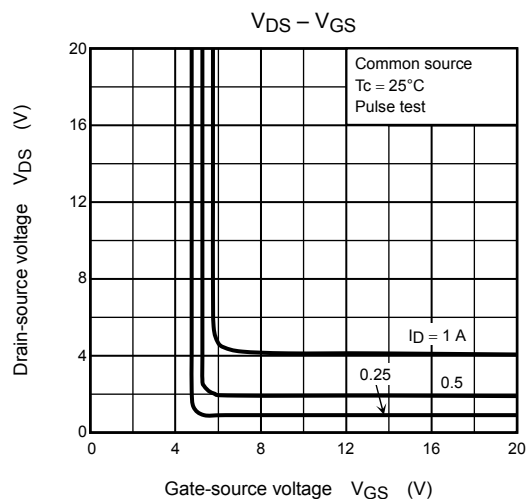
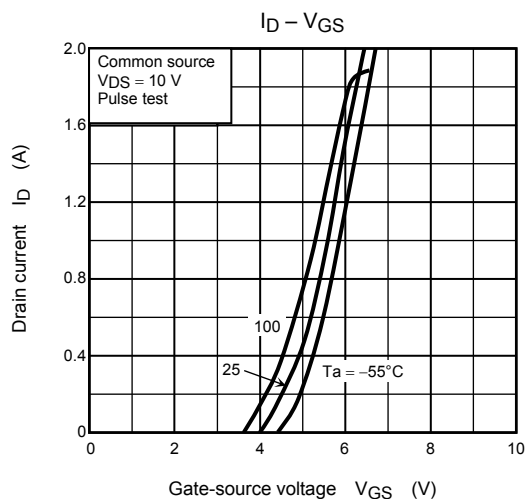
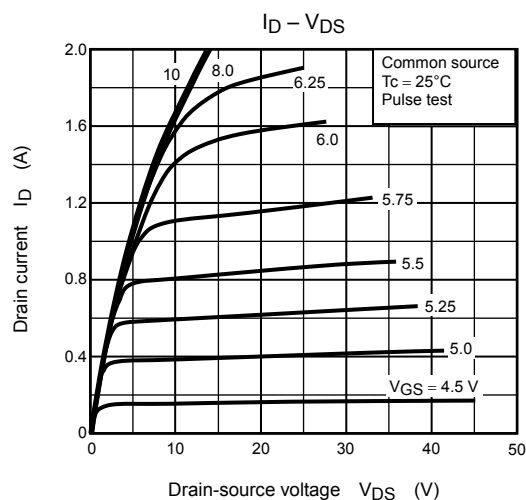
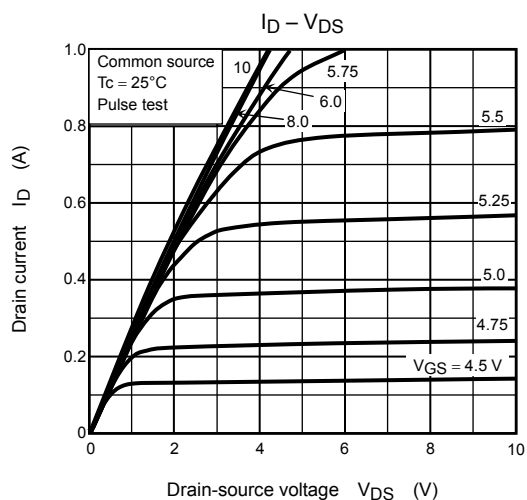
| Characteristic | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--|-----------|---|-----|------|------|---------------|
| Continuous drain reverse current (Note 1) | I_{DR} | — | — | — | 1 | A |
| Pulse drain reverse current (Note 1) | I_{DRP} | — | — | — | 2 | A |
| Forward voltage (diode) | V_{DSF} | $I_{DR} = 1 \text{ A}, V_{GS} = 0 \text{ V}$ | — | — | -1.7 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = 1 \text{ A}, V_{GS} = 0 \text{ V},$ | — | 350 | — | ns |
| Reverse recovery charge | Q_{rr} | $dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$ | — | 1.3 | — | μC |

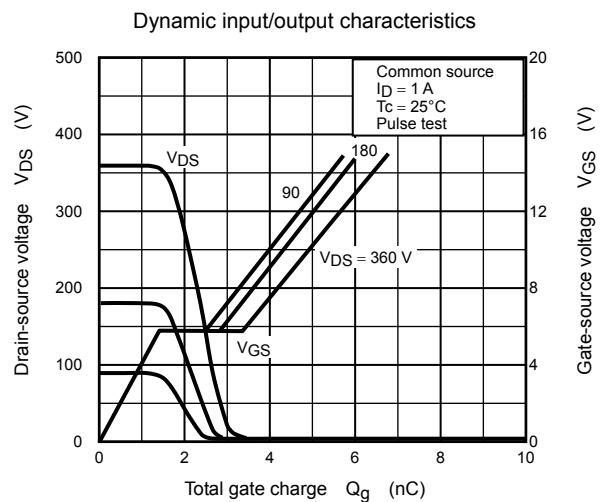
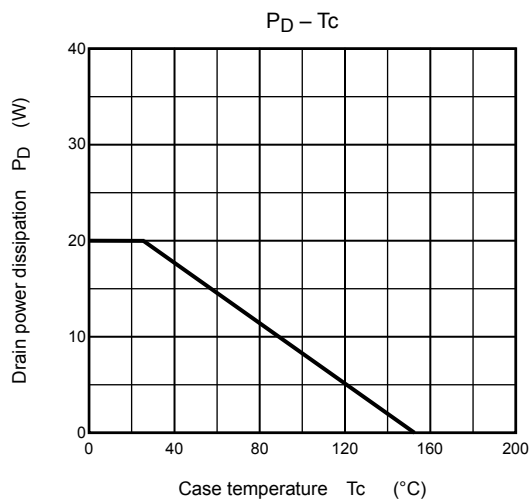
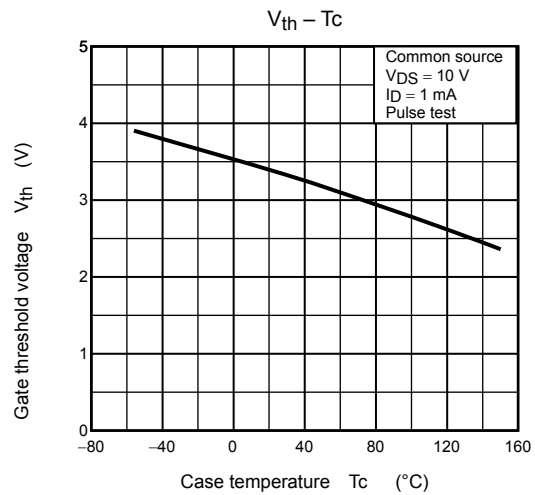
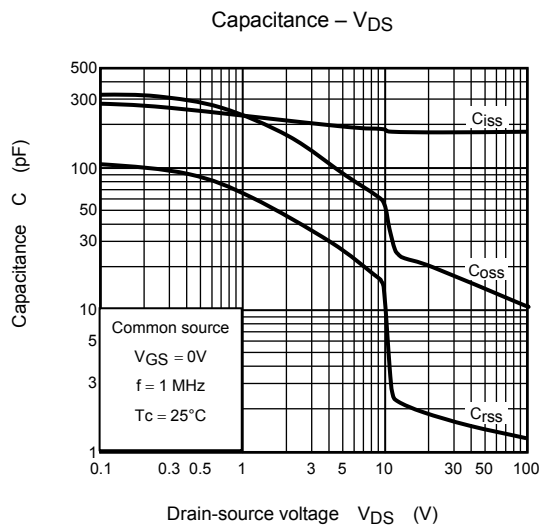
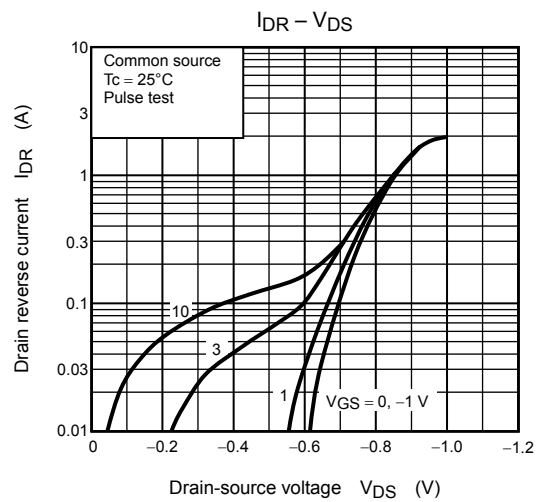
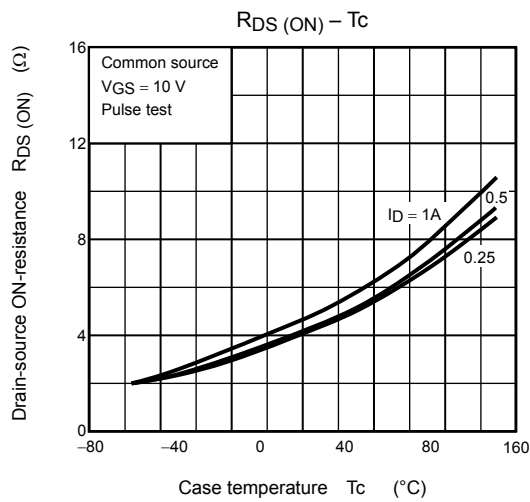
Marking

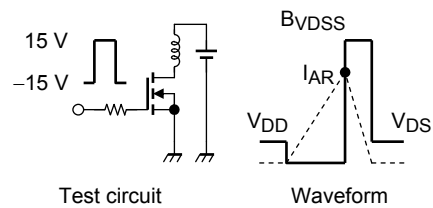
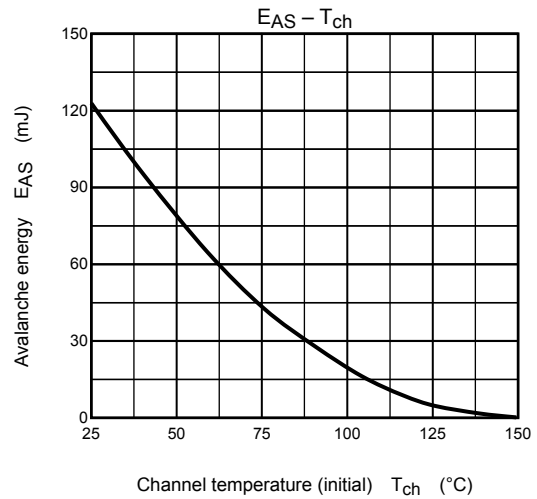
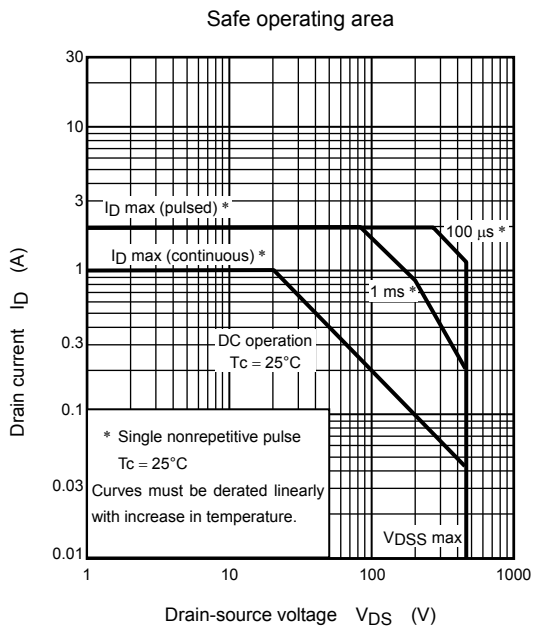
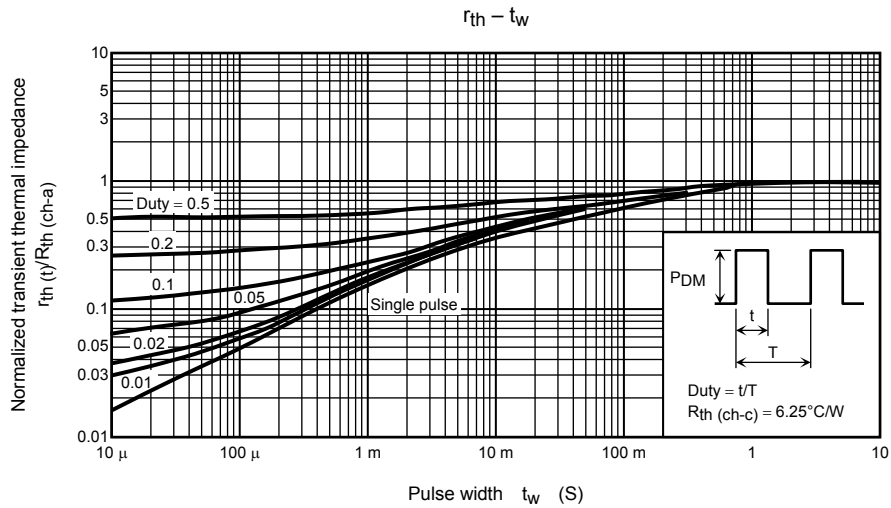


Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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$$R_G = 25 \Omega$$

$$V_{DD} = 90 \text{ V}, L = 203 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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